

| | Type | L # | Hits | Search Text | DBs | Time Stamp |
|---|------|-----|------|---|--|---------------------|
| 1 | BRS | L1 | 2891 | semiconductor and (dmos or (vertical adj (dmos or mos or mosfet or fet))) | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2001/10/19 10:33 |
| 2 | BRS | L2 | 2011 | 1 and source and drain | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2001/10/19 10:36 |
| 3 | BRS | L3 | 87 | 2 and (schottky adj diode) | USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM TDB | 2001/10/19 10:37 |

| | Comments | Error Definition | Errors |
|---|----------|------------------|--------|
| 1 | | | 0 |
| 2 | | | 0 |
| 3 | | | 0 |